NSN 5961-01-241-7919

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-241-7919 **Inclosure Material:** Plastic **Overall Length:** 0.785 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.200 inches **Overall Width:** 0.260 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 40.0 breakdown voltage, collector-to-base, emitter open all transistor and 40.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter all transistor and 70.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**